Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material: Plastic **Overall Length:** 2.280 inches **Terminal Length:** 0.365 inches **Overall Diameter:** 1.405 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Terminal Semiconductor Material: Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 418.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 23.00 amperes source cutoff current universal all semiconductor device diode **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute all semiconductor device diode Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** External surfaces silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 turret Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0